

/ Descriptions

TO-92 PNP Silicon PNP transistor in a TO-92 Plastic Package.

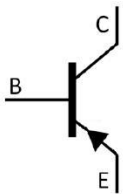
/ Features

1W
One watt high current transistors.

/ Applications

1W
One watt high current amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Collector PIN 2 Base PIN 3 Emitter

/ hFE Classifications & Marking

See Marking Instructions.

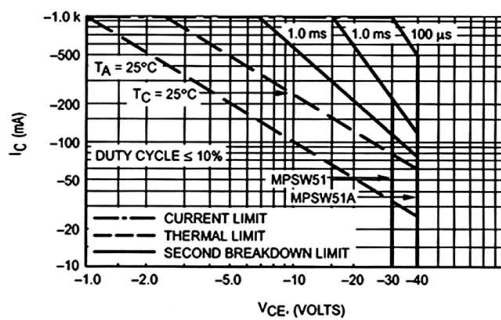
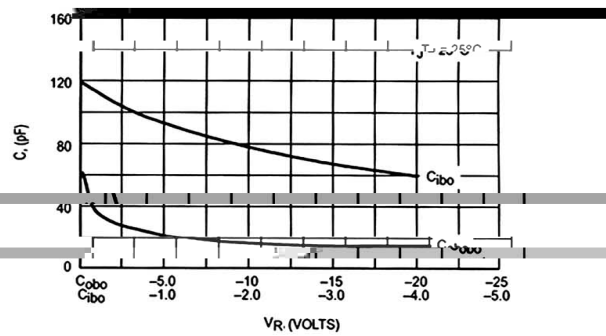
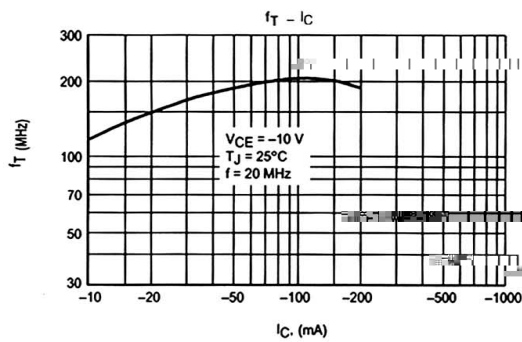
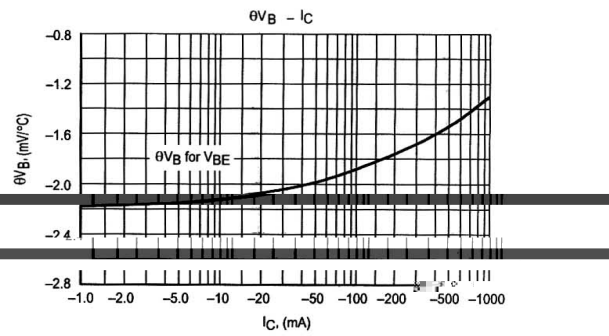
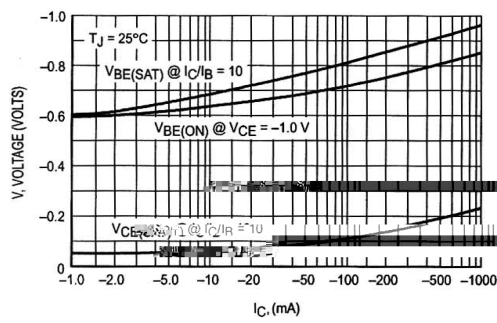
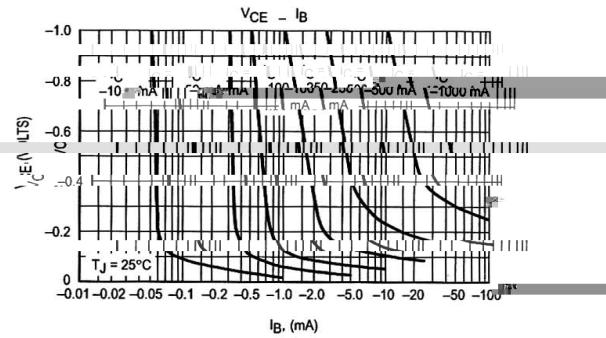
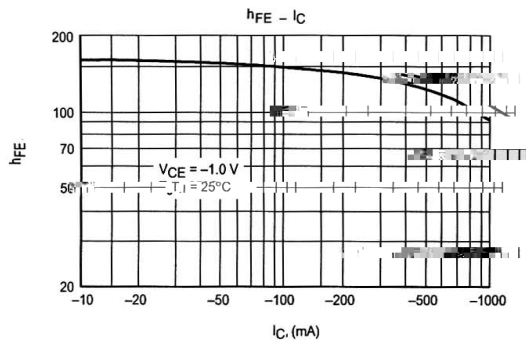
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-40	V
Collector to Emitter Voltage	V_{CEO}	-30	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-1.0	A
Collector Power Dissipation	P_C	1.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=-0.1mA$ $I_E=0$	-40			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-1.0mA$ $I_B=0$	-30			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=-0.1mA$ $I_C=0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-30V$ $I_E=0$			-0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-3.0V$ $I_C=0$			-0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-1.0V$ $I_C=-100mA$	60		320	
	$h_{FE(2)}$	$V_{CE}=-1.0V$ $I_C=-10mA$	55			
	$h_{FE(3)}$	$V_{CE}=-1.0V$ $I_C=-1.0A$	50			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-1.0A$ $I_B=-100mA$			-0.7	V
Base to Emitter On Voltage	$V_{BE(ON)}$	$V_{CE}=-1.0V$ $I_C=-1.0A$			-1.2	V
Transition Frequency	f_T	$V_{CE}=-10V$ $f=20MHz$ $I_C=-50mA$	50			MHz
Output Capacitance	C_{ob}	$V_{CB}=-10V$ $f=1.0MHz$ $I_E=0$		30		pF

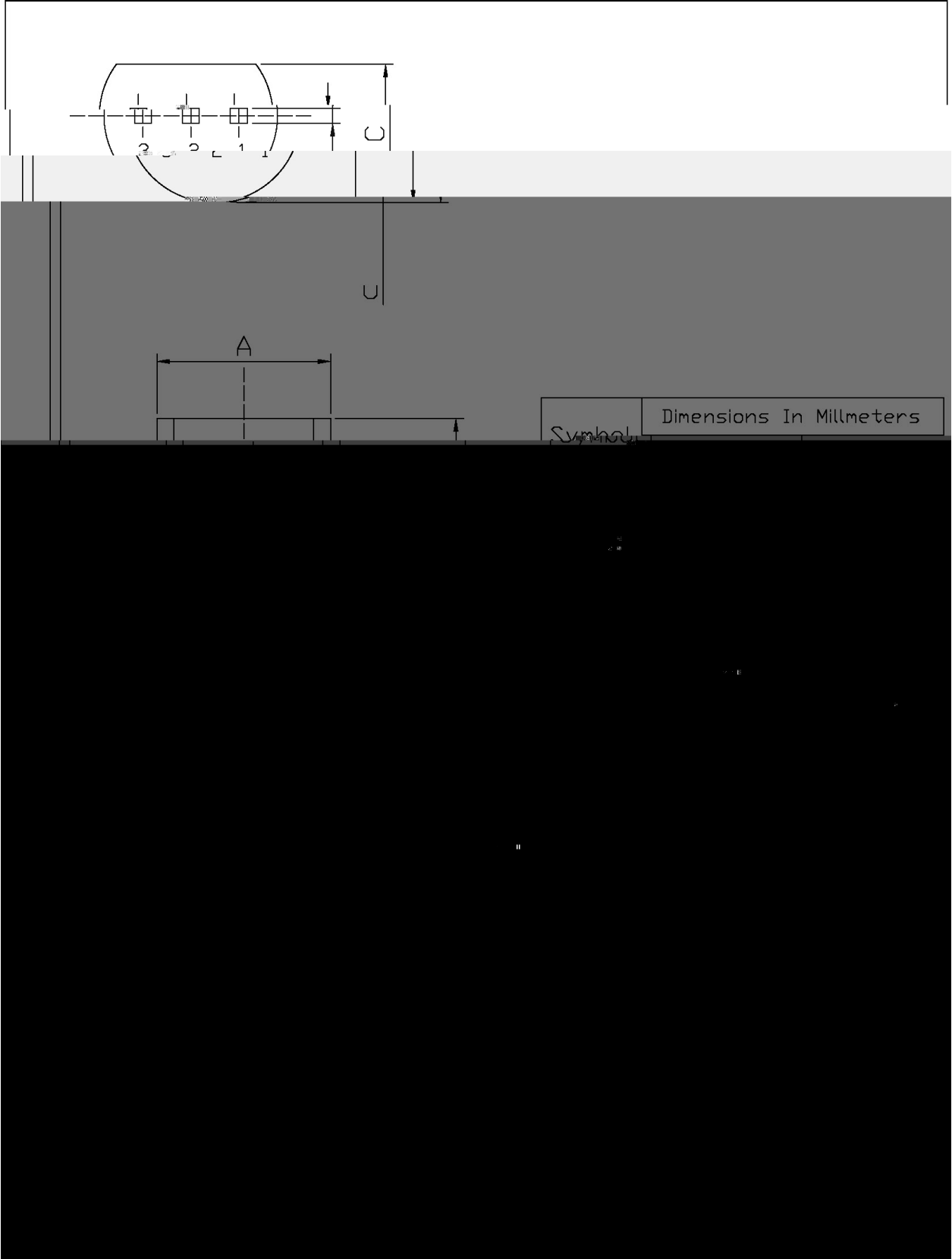
/ Electrical Characteristic Curve



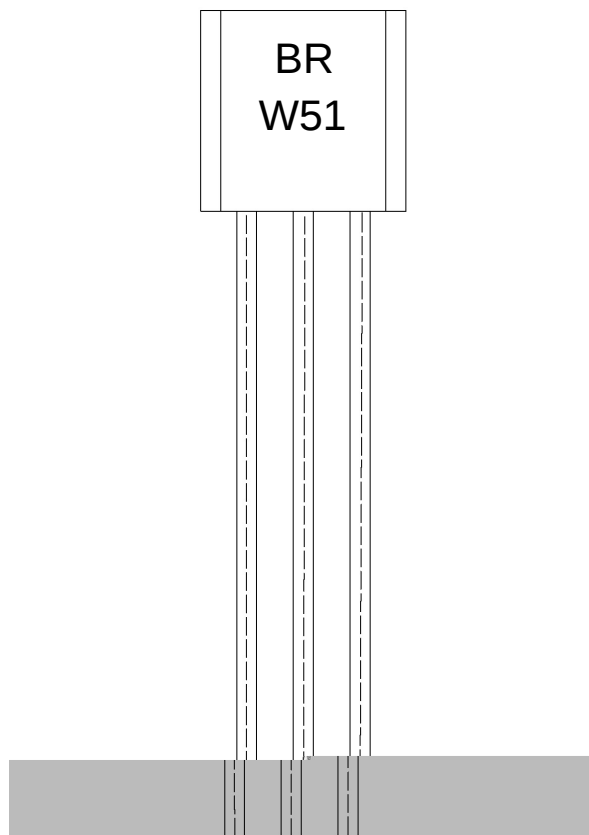
/ Package Dimensions

TO-92

Unit: mm



/ Marking Instructions



BR:

W51

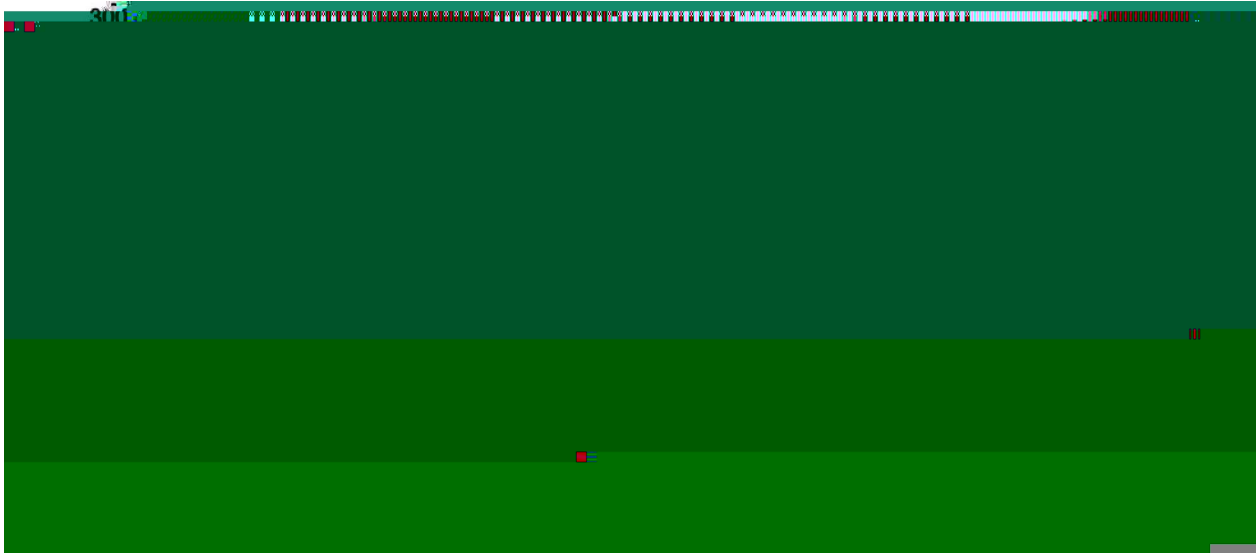
Note:

BR: Company Code.

W51: Product Type.

****: Lot No. Code,code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	只袋	袋盒	只盒	盒箱	只箱	袋	盒	箱

/ AMMO

Package Type 封装形式	Units 包装数量		Dimension 包装尺寸 (unit: mm3)
	只纸带	纸带盒	